

15 AMP SILICON BRIDGE RECTIFIERS

FEATURES

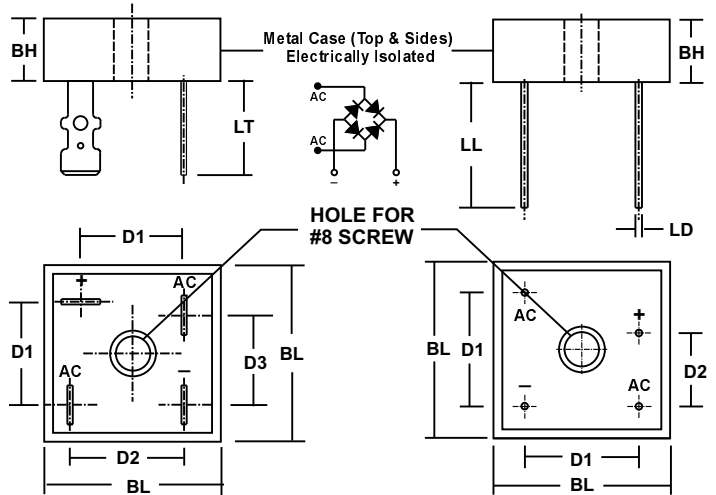
- **VOID FREE VACUUM DIE SOLDERING FOR MAXIMUM MECHANICAL STRENGTH AND HEAT DISSIPATION (Solder Voids: Typical < 2%, Max. < 10% of Die Area)**
- **BUILT-IN STRESS RELIEF MECHANISM FOR SUPERIOR RELIABILITY AND PERFORMANCE**
- **ELECTRICALLY ISOLATED METAL CASE FOR MAXIMUM HEAT DISSIPATION**
- **UL RECOGNIZED - FILE #E124962**
- **RoHS COMPLIANT**

MECHANICAL DATA

- Case: Metal (Potting epoxy carries U/L flammability Rating 94V-0)
- Terminals: Round silver plated copper pins or fast-on terminals
- Soldering: Per MIL-STD 202 Method 208 guaranteed
- Polarity: Marked on side of case
- Mounting Position: Any. Through hole for #8 screw.
Max. mounting torque = 20 in-lb.
- Weight: Fast-on Terminals - 1.1 Ounces (31.6 Grams)
Wire Leads - 0.95 Ounce (28.5 Grams)

MECHANICAL SPECIFICATION

SERIES: DB1500 - DB1510 and ADB1504 - ADB1508



SYM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
BL	28.4	28.7	1.12	1.13
BH	11.0	11.2	0.43	0.44
D1	15.7	16.7	0.62	0.66
D2	17.5	18.5	0.69	0.73
D3	13.5	14.5	0.53	0.57
LT	n/a	14.2	n/a	0.56

SYM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
BL	28.4	28.7	1.12	1.13
BH	11.0	11.2	0.43	0.44
D1	17.5	18.5	0.69	0.73
D2	10.9	11.9	0.43	0.47
LL	20.6	n/a	0.81	n/a
LD	1.0	1.1	0.039	0.042

Suffix "T" indicates FAST-ON TERMINALS

Suffix "W" indicates WIRE LEADS

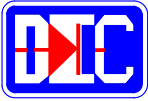
MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%.

PARAMETER (TEST CONDITIONS)	SYMBOL	RATINGS										UNITS
		CONTROLLED AVALANCHE			NON-CONTROLLED AVALANCHE							
		ADB 1504	ADB 1506	ADB 1508	DB 1500	DB 1501	DB 1502	DB 1504	DB 1506	DB 1508	DB 1510	
Series Number												
Maximum DC Blocking Voltage	V _{RM}											
Working Peak Reverse Voltage	V _{RWM}	400	600	800	50	100	200	400	600	800	1000	VOLTS
Maximum Peak Recurrent Reverse Voltage	V _{RRM}											
RMS Reverse Voltage	V _{R (RMS)}	280	420	560	35	70	140	280	420	560	700	
Peak Forward Surge Current. Single 60Hz Half-Sine Wave Superimposed on Rated Load (JEDEC Method). T _J = 125° C.	I _{FSM}	400										AMPS
Average Forward Rectified Current @ T _c = 75° C.	I _O	15										
Junction Temperature Range	T _J	-55 to +135										°C
Storage Temperature Range	T _{STG}	-55 to +135										
Minimum Avalanche Voltage	V _{(BR) Min}	See Note 1			n/a							VOLTS
Maximum Avalanche Voltage	V _{(BR) Max}	See Note 1			n/a							
Maximum Forward Voltage (Per Diode) at 7.5 Amps DC	V _{FM}	1.05										
Maximum Reverse Current at Rated V _{RM} @ T _A = 25° C @ T _A = 125° C	I _{RM}	1 50										μA
Minimum Insulation Breakdown Voltage (Circuit to Case)	V _{ISO}	2000										VDC
Typical Thermal Resistance, Junction to Case	R _{θJC}	1.6										°C/W

NOTES: (1) These bridges exhibit the avalanche characteristic at breakdown. If your application requires a specific breakdown voltage range, please contact us.

3.01 1500B



15 AMP SILICON BRIDGE RECTIFIERS

RATING & CHARACTERISTIC CURVES FOR SERIES DB1500 - DB1510 and SERIES ADB1504 - ADB1508

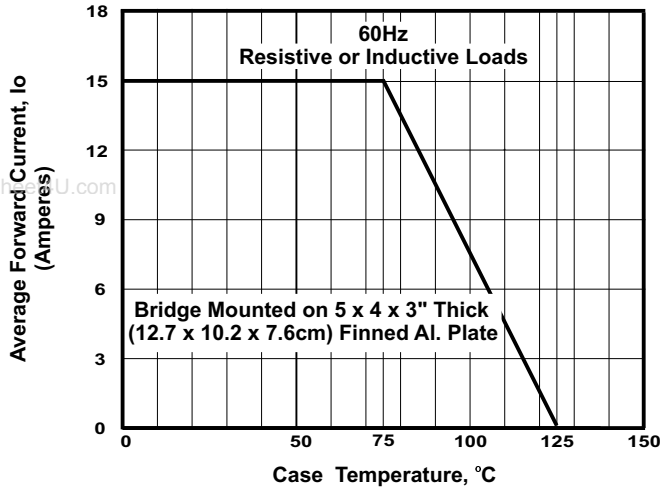


FIGURE 1. FORWARD CURRENT DERATING CURVE

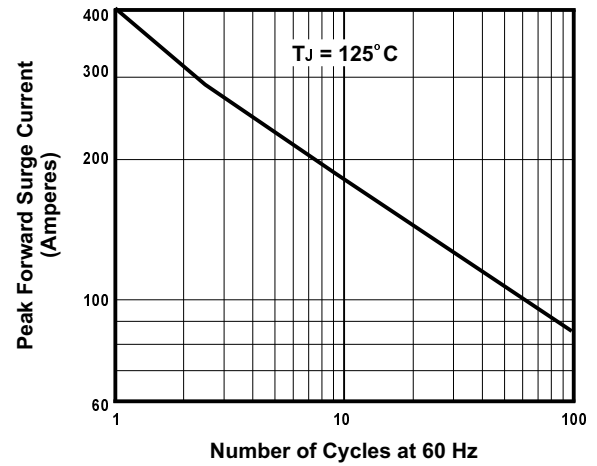


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

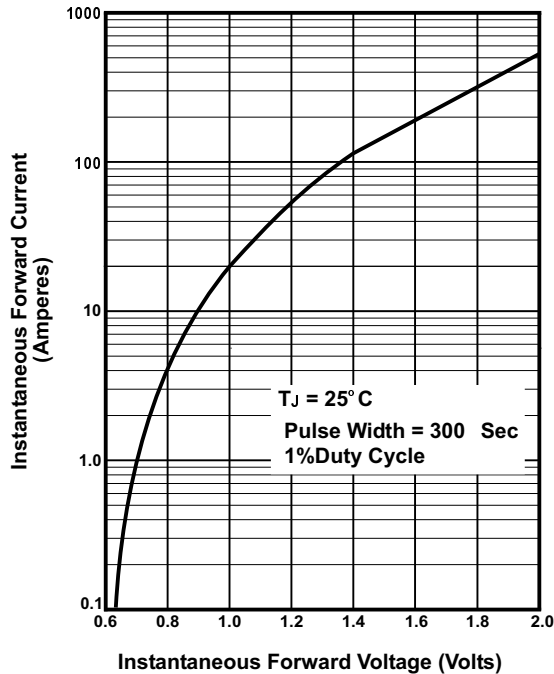


FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE

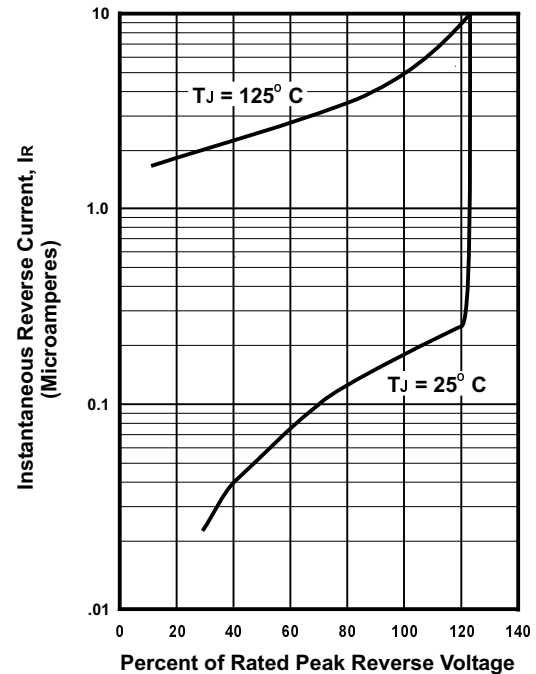


FIGURE 4. TYPICAL REVERSE CHARACTERISTICS